Electronic Supplementary Material (ESI) for RSC Advances.

Precision Excimer Laser Annealed Ga-doped ZnO Electron Transport Layer for Perovskite Solar Cells

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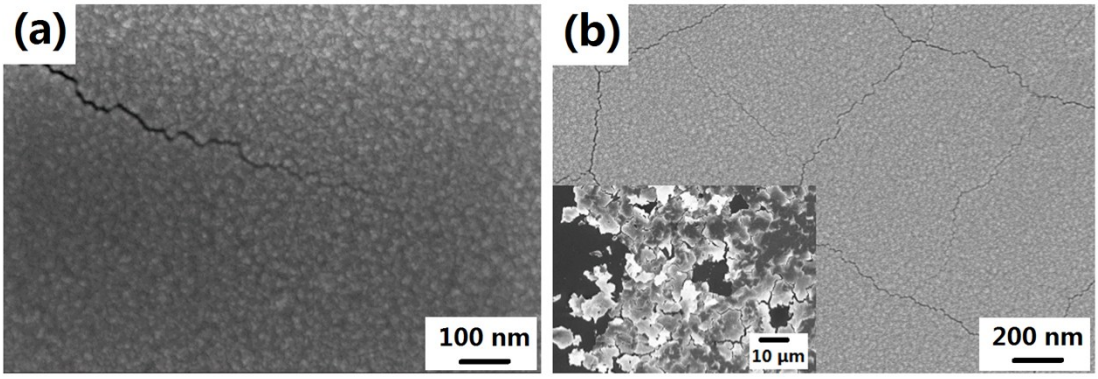

Fig S1 Surface SEM images of (a) ELA 90-30 and (b) ELA 105-1, the inset is ELA 105-20.

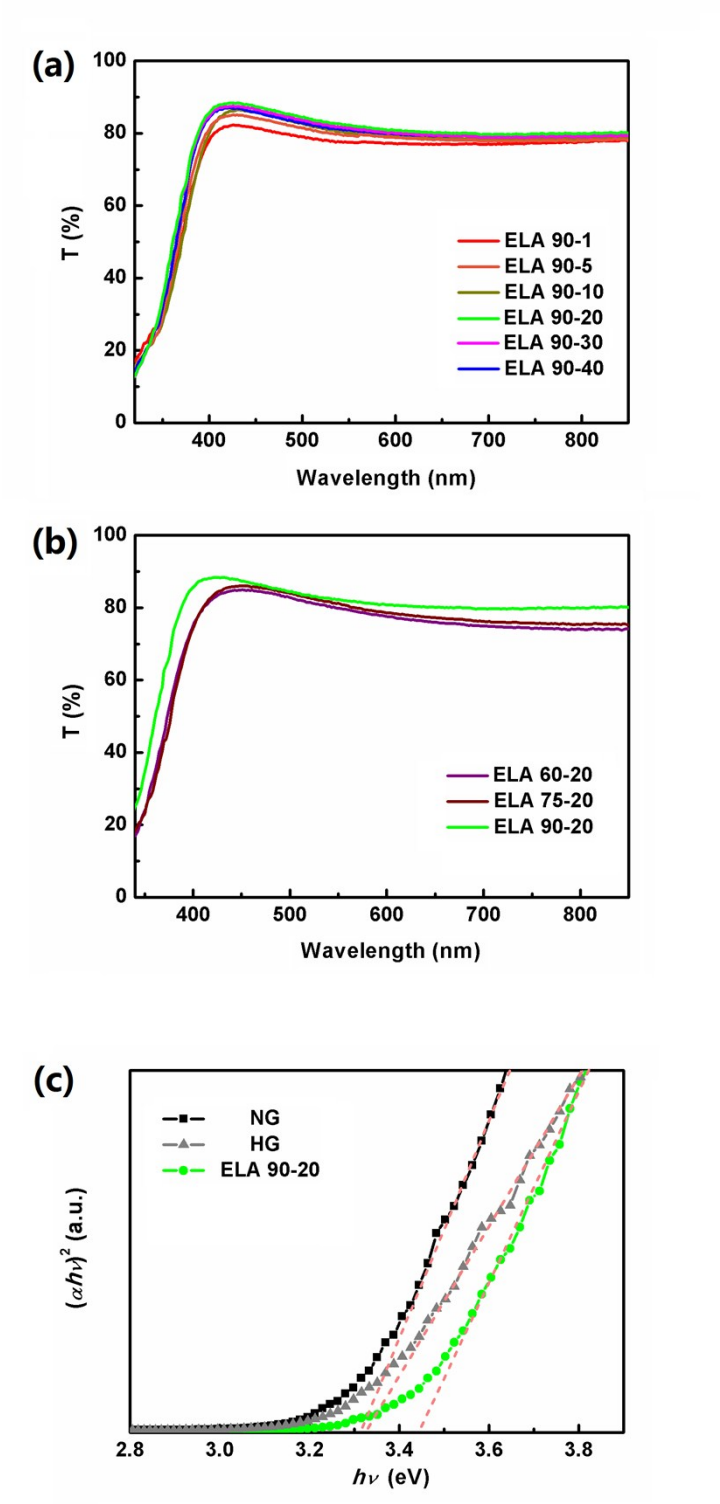

Fig S2 Transmittance spectra of GZO films with ELA treatment when (a) laser fluence is fixed at 90 mJ cm^{-2} and (b) pulse counts are fixed at 20. (c) $(\alpha hv)^2$ vs hv plots of the GZO films with different treatments.

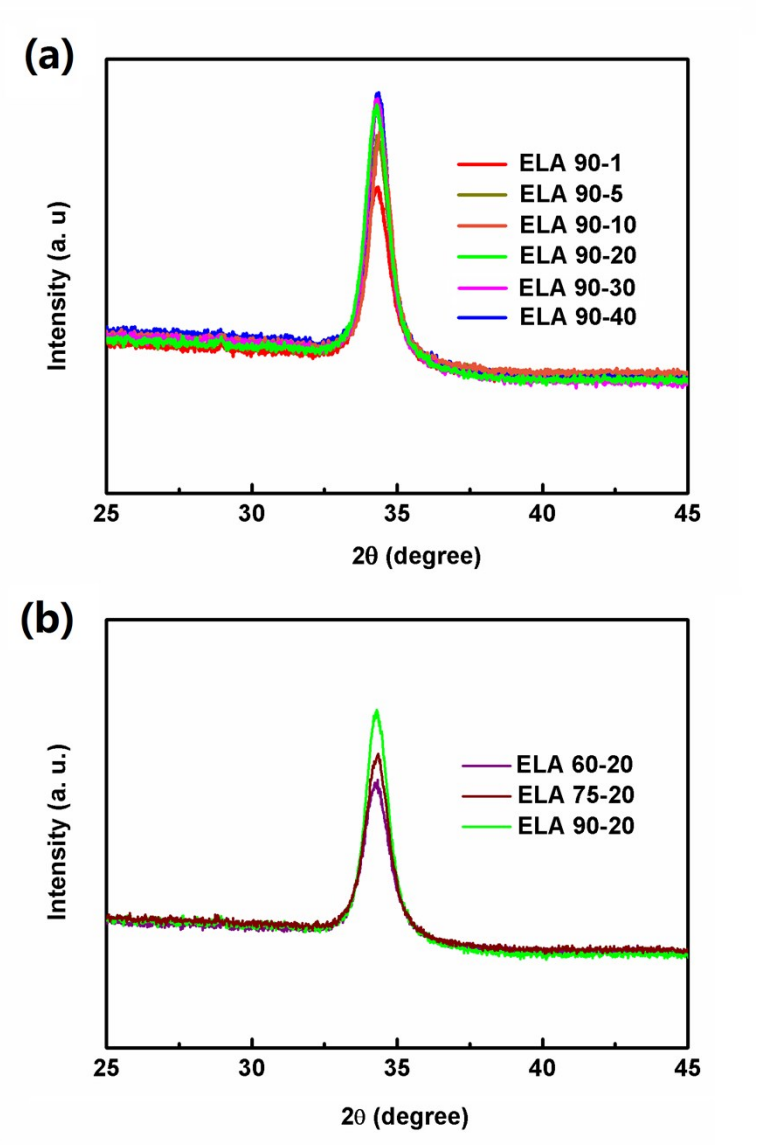

Fig S3 XRD patterns of GZO films with ELA treatment when (a) laser fluence is fixed at 90 mJ cm^{-2} and (b) pulse counts are fixed at 20.

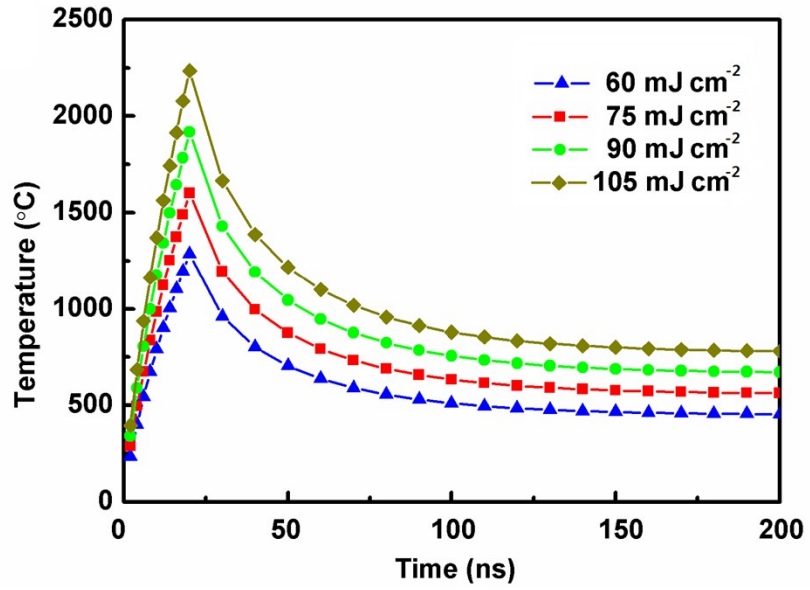

Fig. S4 Variation of the surface temperature with the time after loading 1 pulse with different fluence.

Table S1 Parameters used in ANSYS simulation process[1-3]. When $t = 0$, $t = T_0$ (27 °C), it is assumed that there is no heat loss on the surface of the films and the thickness of the sample is sufficient for the diffusion of heat inside[4].

Parameters	GZO	Glass
Density (kg/m³)	5675	2400
Specific heat capacity J (kg K)$^{-1}$	552	837
Thermal conductivity (W m^{-1} K^{-1})	23.4	1.1
Melt point (°C)	1975	800

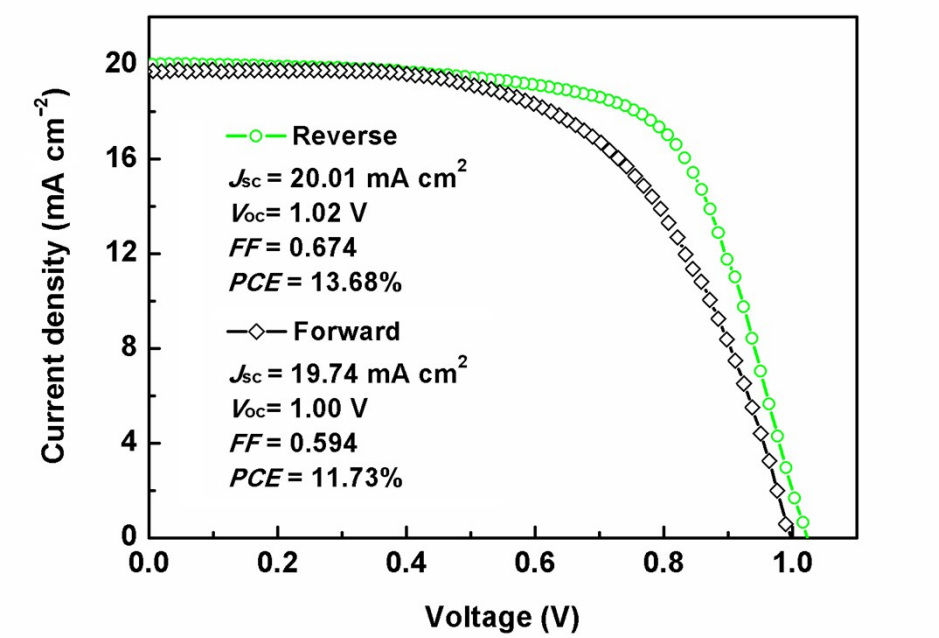

Fig. S5 Hysteresis analysis of the devices based on ELA 90-20 at a scan rate of 50 mV s^{-1}

Reference

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